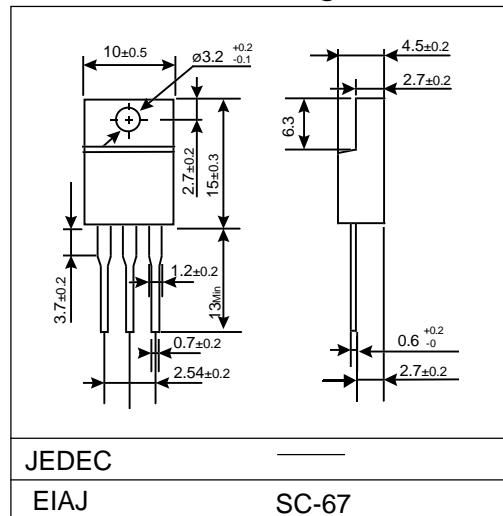


YG801C06R

(60V / 5A TO-22OF15)

SCHOTTKY BARRIER DIODE

■ Outline Drawings



■ Features

- Low VF
 - Super high speed switching.
 - High reliability by planer design.

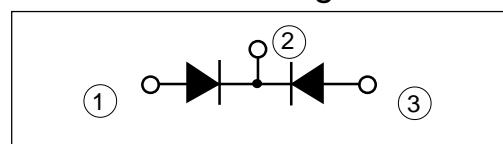
■ Applications

- High speed power switching.

■ Maximum Ratings and Characteristics

- Absolute Maximum Ratings

■ Connection Diagram



Item	Symbol	Conditions	Rating	Unit
Repetitive peak reverse voltage	V _{RRM}		60	V
Repetitive peak surge reverse voltage	V _{RSM}	t _w =500ns, duty=1/40	60	V
Isolating voltage	V _{iso}	Terminals to Case, AC. 1min.	1500	V
Average output current	I _O	duty=1/2, T _C =125°C Square wave	5*	A
Surge current	I _{FSM}	Sine wave 10ms	60	A
Operating junction temperature	T _j		-40 to +150	°C
Storage temperature	T _{stg}		-40 to +150	°C

* Out put current of centertap full wave connection.

- Electrical Characteristics (Ta=25°C Unless otherwise specified)

Item	Symbol	Conditions	Max.	Unit
Forward voltage drop **	V_F	$I_F=2.0A$	0.58	V
Reverse current **	I_R	$V_R=V_{RRM}$	5.0	mA
Thermal resistance	$R_{th(j-c)}$	Junction to case	5.0	°C/W

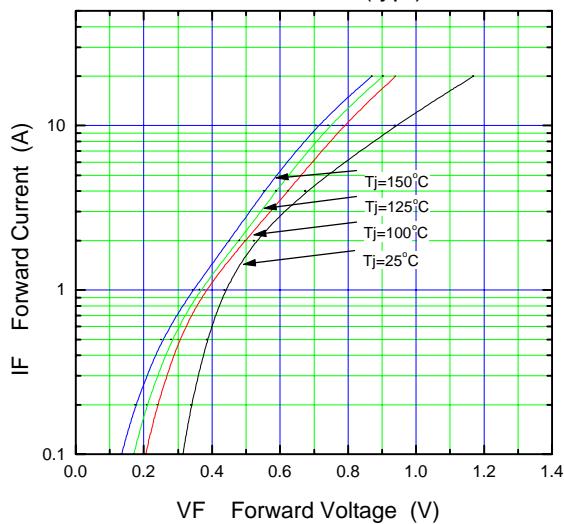
** Rating per element

- Mechanical Characteristics

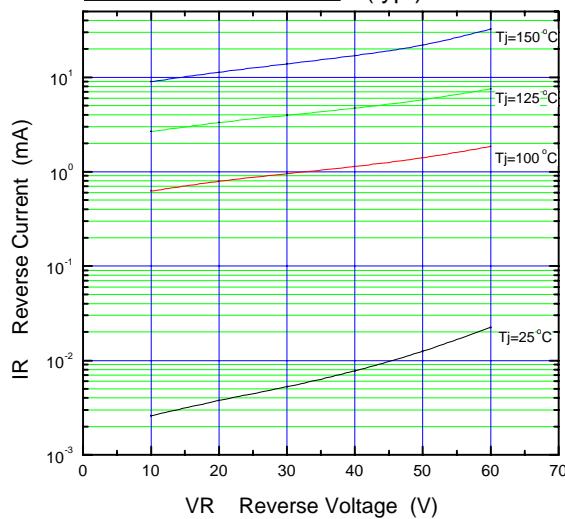
Mounting torque	Recommended torque	0.3 to 0.5	N · m
Weight		2.3	g

■ Characteristics

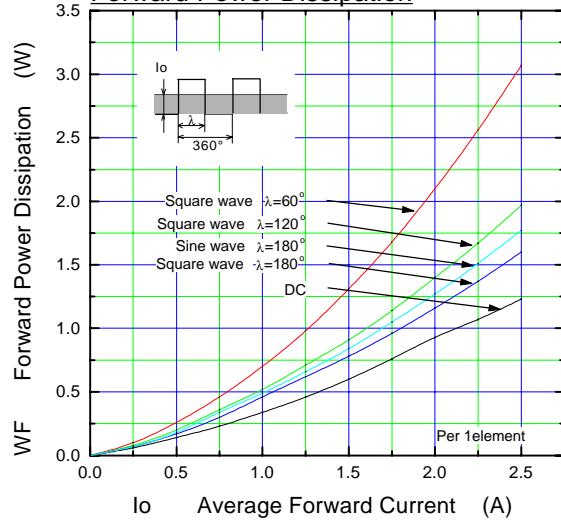
Forward Characteristic (typ.)



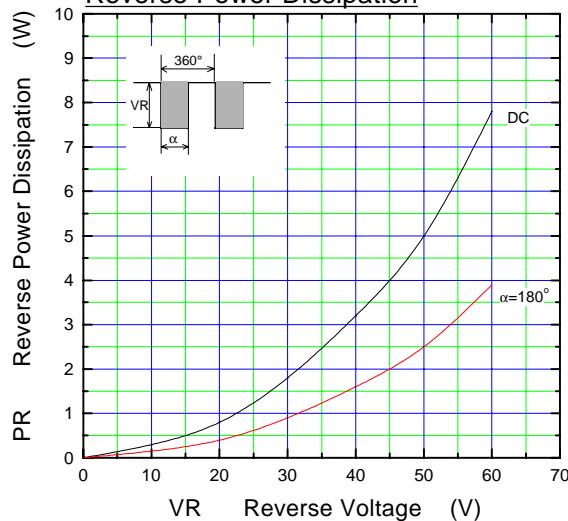
Reverse Characteristic (typ.)



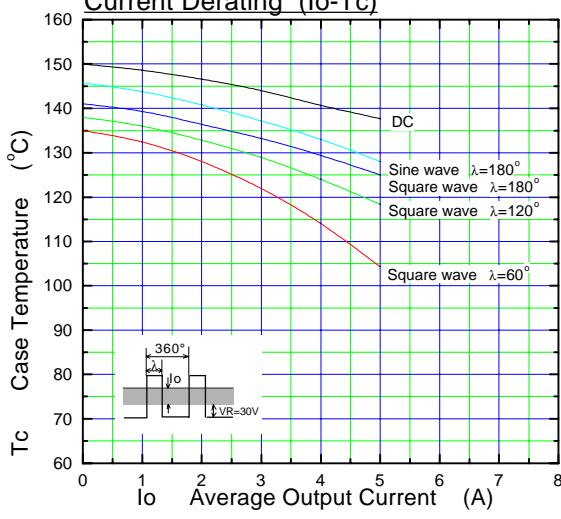
Forward Power Dissipation



Reverse Power Dissipation



Current Derating (Io-Tc)



λ: Conduction angle of forward current for each rectifier element
Io: Output current of center-tap full wave connection

Junction Capacitance Characteristic (typ.)

